## 2SB1683 / 2SD2639



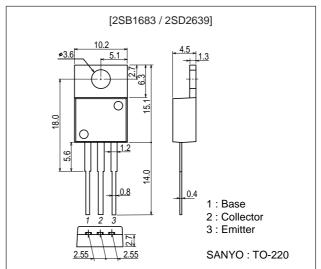
# 140V / 12A, AF 60W Output Applications

#### **Features**

- · Wide ASO because of on-chip ballast resistance.
- Good dependence of fT on current and good HF characteristic.

## **Package Dimensions**

unit : mm 2010C



## **Specifications**

(): 2SB1683

### **Absolute Maximum Ratings** at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		(-)160	V
Collector-to-Emitter Voltage	VCEO		(-)140	V
Emitter-to-Base Voltage	VEBO		(-)6	V
Collector Current	IC		(-)12	Α
Collector Current (Pulse)	ICP		(-)15	Α
Collector Dissipation	PC	Tc=25°C	80	W
Junction Temperature	Tj		150	ô
Storage Temperature	Tstg		-40 to +150	ô

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
r alametei			min	typ	max	Offic
Collector Cutoff Current	ICBO	V <sub>CB</sub> =(-)80V, I <sub>E</sub> =0			(-)0.1	mA
Emitter Cutoff Current	IEBO	VEB=(-)4V, IC=0			(-)0.1	mA

Continued on next page.

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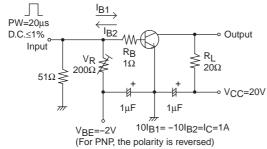
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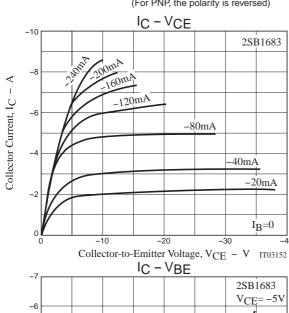
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
DC Current Gain	hFE1	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)1A	60*		200*	
	hFE2	VCE=(-)5V, IC=(-)6A	20			
Gain-Bandwidth Product	fŢ	VCE=(-)5V, IC=(-)1A		15		MHz
Output Capacitance	Cob	V <sub>CB</sub> =(-)10V, f=1MHz		(300)210		pF
Base-to-Emitter Saturation Voltage	VBE	VCE=(-)5V, IC=(-)1A			1.5	V
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=(-)5A, IB=(-)0.5A		(1.1)0.6	2.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I <sub>C</sub> =(-)5mA, I <sub>E</sub> =0	(-)160			V
Collector to Emitter Breekdown Voltage	V(BR)CEO	I <sub>C</sub> =(-)5mA, R <sub>BE</sub> =∞	(-)140			V
Collector-to-Emitter Breakdown Voltage		IC=(-)50mA, RBE=∞	(-)140			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =(-)5mA, I <sub>C</sub> =0	(-)6			V
Turn-ON Time	ton	See specified test circuit.		(0.25)0.26		μs
Fall Time	tf	See specified test circuit.		(0.53)0.68		μs
Storage Time	t <sub>stg</sub>	See specified test circuit.		(1.61)6.88		μs

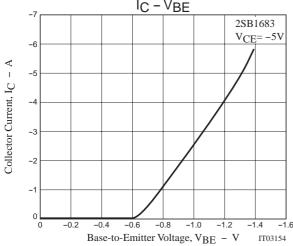
#### \*: The 2SB1683 / 2SD2639 are classified by 1A hFE as follows:

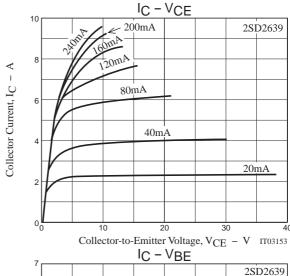
Rank	D	E		
hFE	60 to 120	100 to 200		

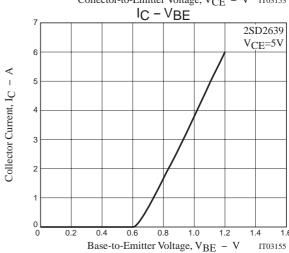
## **Switching Time Test Circuit**

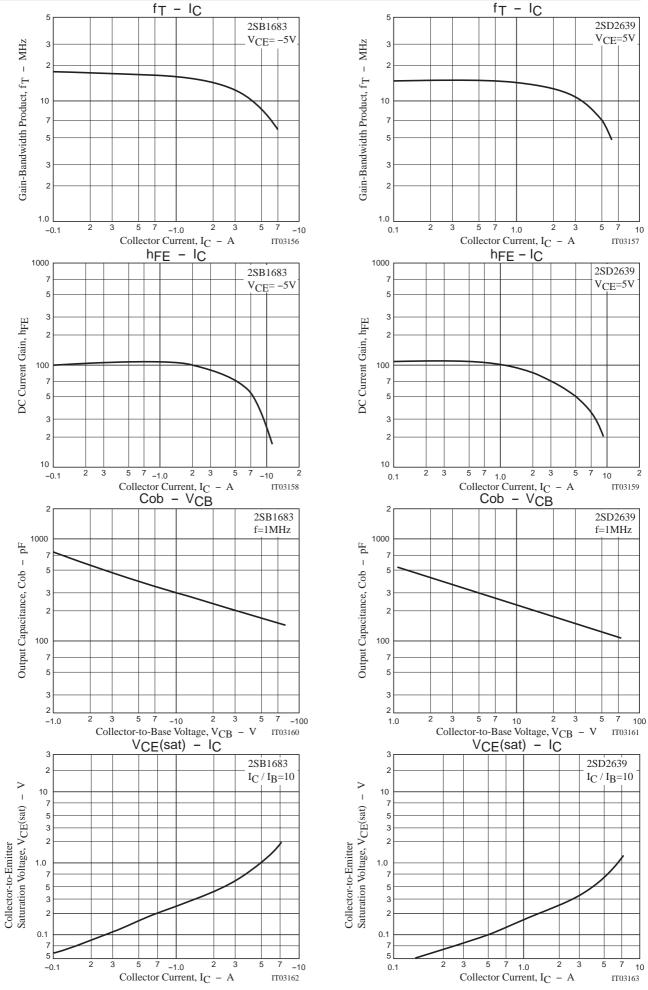




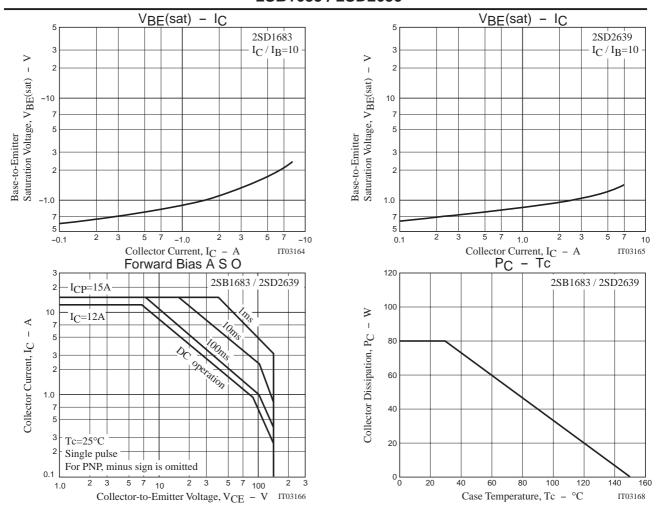








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